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NCP398

USB Type-C VCONN Overvoltage Protection IC

The NCP398 is an overvoltage protection device. It protects VCONN against overvoltages in applications where VCONN is directly derived from the VBUS supply.

At power up, the integrated power MOSFET is automatically controlled to reduce inrush current. The IC continuously monitors undervoltage, overvoltage and thermal events. In case of overvoltage, a very high speed comparator opens the power MOSFET instantaneously.

The part is enabled through the $\overline{EN}$ pin. A high level on this pin allows forcing off the internal switch and drastically decreases the current consumption of the NCP398 core.

Features

- Over−voltage Protection up to + 28 V
- On−chip Low R_{dson} NMOS Transistors: Typical 200 mΩ
- Over−voltage Lockout (OVLO)
- Shutdown $\overline{EN}$ Input
- Output Discharge Path
- WLCSP4 Package 0.84 x 0.84 mm, 0.4p
- UDFN6 Package 2 x 2 mm, 0.65p
- These Parts are ROHS Devices

Typical Applications

- Type−C USB
- Smartphones
- Tablets

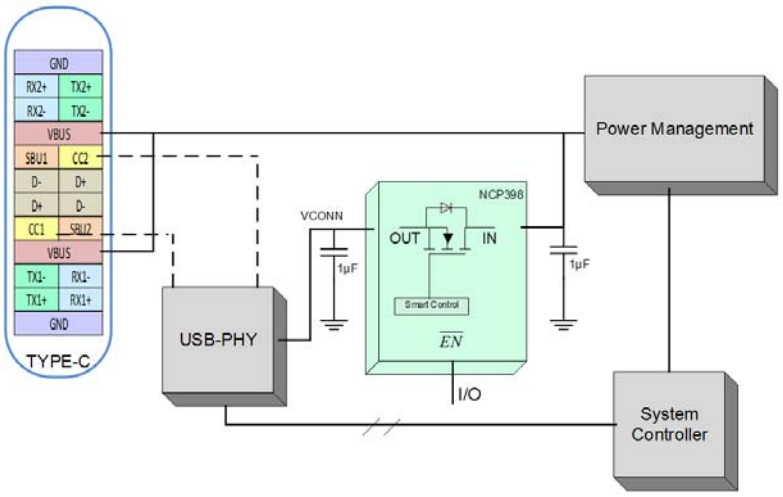

Figure 1. Typical Application Circuit

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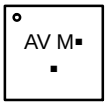
MARKING DIAGRAMS

UDFN6
CASE 517AB

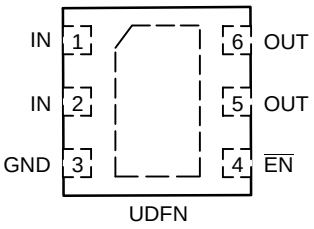


AV = Specific Device Code
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

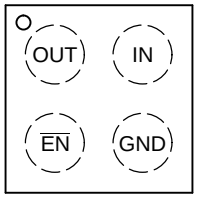
WLCSP4
CASE 567MN

AA = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week

PIN CONNECTIONS



UDFN



WLCSP

(Top Views)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

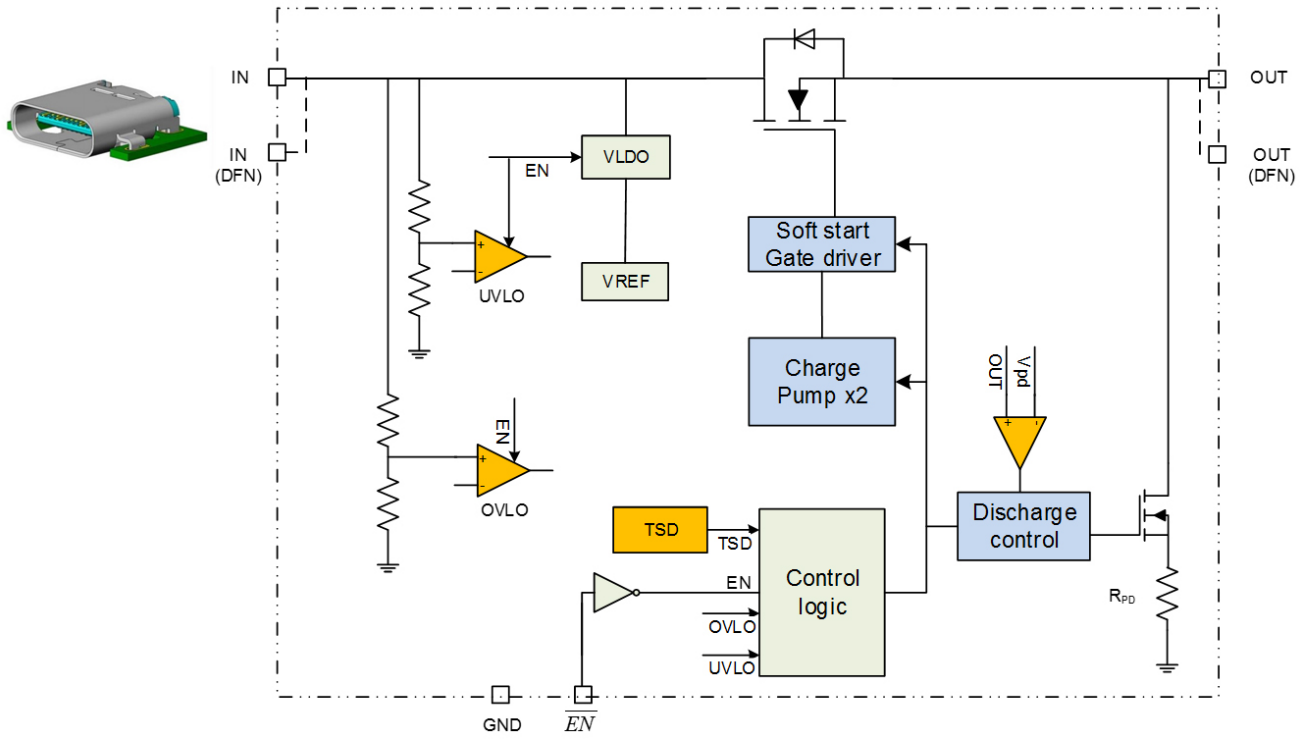


Figure 2. Simplified Block Diagram, WLCSP and UDFN Packages

Table 1. CSP PINOUT DESCRIPTION

Pin	Pin Name	Type	Description
A1	OUT	OUTPUT	Output voltage pin. The OUT pin must be connected to the circuitry that is to be protected (VCONN rail).
B1	$\overline{EN}$	I/O	Enable pin bar. The device enters in shutdown mode when this pin is tied high in which case the output is disconnected from the input.
A2	IN	POWER	Input voltage pin. The IN pin must be connected to the input power supply (VBUS).
B2	GND	POWER	Ground. Must be connected to the system GND plane.

Table 2. DFN PINOUT DESCRIPTION

Pin	Pin Name	Type	Description
1,2	IN	POWER	Input voltage pins. The two IN pins must be hardwired together and are connected to the input power supply (VBUS).
3	GND	POWER	Ground. Must be connected to the system GND plane.
5,6	OUT	POWER	Output voltage pins. The two OUT pins must be hardwired together and are connected to the circuitry that is to be protected (VCONN rail).
4	$\overline{EN}$	I/O	Enable pin bar. The device enters in shutdown mode when this pin is tied high in which case the output is disconnected from the input.
7	PAD	POWER	DFN package back side pad. Must be connected to ground plane for thermal dissipation optimization.

Table 3. MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Minimum Voltage (All to GND)		V_{MIN}	−0.3	V
Maximum Voltage (Ins to GND)		V_{INMAX}	29	V
Maximum Voltage (All others to GND)		V_{MAX}	7	V
Maximum DC current		I_{MAX}	0.8	A
Thermal Resistance, Junction to Air	WLCSP (Note 1) DFN (Note 1)	$R_{\theta JA}$	170 145	°C/W
Operating Ambient Temperature Range		T_A	−40 to +85	°C
Storage Temperature Range		T_{STG}	−65 to +150	°C
Junction Operating temperature		T_J	+125	°C
Human Body Model (HBM) ESD Rating are (Note 2)		ESD HBM	2	kV
Charged Device Model (CDM) ESD Rating are (Note 2)		ESD CDM	1	kV
Latch Up Current (Note 3)		I_{LU}	100	mA
Moisture Sensitivity		MSL	Level 1	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The $R_{\theta JA}$ is highly dependent on the PCB heat sink area. As example UDFN6 $R_{\theta JA}$ is 220°C/W with 50 mm^2 (copper 35 μm, 1 oz) and 145°C/W with 200 mm^2 (copper 35 μm, 2 oz).
2. Human Body Model, 100 pF discharged through a 1.5 kΩ resistor following specification JESD22/A114, Charged Device Model (CDM) per JEDEC standard: JESD22−C101 Class IV.
3. Latch Up Current per JEDEC standard: JESD78 class II.

Table 4. ELECTRICAL CHARACTERISTICS
Min / Max limits values (−40°C < T_A < +85°C) and V_{IN} = +5 V (Unless otherwise noted). Typical values are T_A = +25°C.

Characteristics	Symbols	Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{IN}		−	−	28	V
Under Voltage Lockout	UVLO	Vin rising	2.4	−	2.8	V
Under Voltage Lockout Hysteresis	$UVLO_{HYST}$	Vin falling	−	50	−	mV
Over voltage Lockout Threshold	OVLO (Note 4)	Vin rising	5.50	5.65	5.80	V
Over voltage Lockout Threshold hysteresis	$OVLO_{HYST}$	Vin falling	−	115	−	mV
Vin versus Vout Resistance	R_{DSON}	Vin = 5 V, $\overline{EN}$ = low, 25°C, WLCSP	−	190	220	mΩ
		–40°C < T_J < 85°C, WLCSP	−	230	260	
		Vin = 5 V, $\overline{EN}$ = low, 25°C, UDFN	−	230	260	
		–40°C < T_J < 85°C, UDFN	−	270	300	
Supply Quiescent Current	I_{DD}	No load. $\overline{EN}$ = low	−	40	60	μA
OFF current	I_{OFF}	$\overline{EN}$ = high	−	−	1.5	μA
Standby current	I_{STB}	Vin = 2.4 V	−	−	2.5	μA
Output Discharge path	R_{PD}	From $\overline{EN}$ = low to high or Vin < UVLO – hysteresis to Vout = V_{PD}	8	10	12	kΩ
Output Discharge path level	V_{PD}	Vout falling	−	0.63	−	V
$\overline{EN}$						
$\overline{EN}$ Voltage High	V_{IH}		1.2	−	−	V
$\overline{EN}$ Voltage Low	V_{IL}		−	−	0.4	V
$\overline{EN}$ Input Leakage Current	$I_{\overline{EN}}$	0 < $V_{\overline{EN}}$ < 5.5 V	−1	0	+1	μA
TIMINGS						
Ton Time	T_{ON}	Vin valid, From $\overline{EN}$ high to low, 90% Vout	−	0.3	1	ms
Disable Time	T_{OFF}	From $\overline{EN}$ low to high, to 90% Vout. R_{LOAD} 100 Ω	−	10	−	μs
OVLO Turn Off Time	T_{OVLO}	Vin exceeding V_{OVLO} at 2 V/μs to Vout starts decreasing. R_{LOAD} 100 Ω	−	100	−	ns
TSD						
Thermal shutdown	TSD		−	150	−	°C
Thermal shutdown rearming	TSD rearm		−	125	−	°C

4. Please contact your ON representative for additional OVLO thresholds.
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Operation

The NCP398 device provides overvoltage protection when a wrong input supply is connected or voltage ringing appears on the input line. The internal NMOS Fet is soft start controlled to limit inrush current into the load (capacitors, IC wake up).

The device integrates an enable control pin, undervoltage and overvoltage comparators, and output discharge path to eliminate residual voltage after the turn off.

Timings Chronogram and States Description

The phase 1 sections described below are respectively the OFF state ($\overline{EN}$ high) and the standby state (VIN < UVLO) of the device. When Vin is below the undervoltage comparator (UVLO) or $\overline{EN}$ is tied high, NCP398 will be in this state.

Phase 2 corresponds to the defined time for the gate driver soft start. Referring to the electrical parameter, this phase is aligned to Ton time.

Phase 3 is the normal operation, with Vin valid, the part enabled and there is no fault.

The behavior during an overvoltage condition is detailed in the phase number 4.

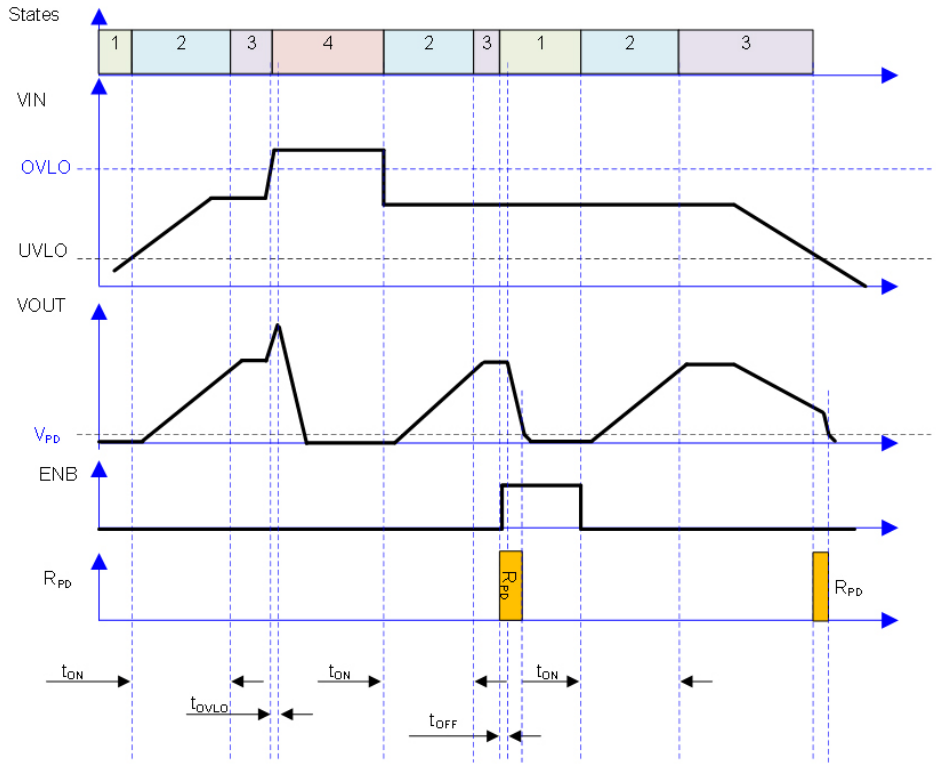


Figure 3. Timings Diagram

Enable Bar Pin ($\overline{EN}$)

The part is enabled through the $\overline{EN}$ pin. In some diagrams and figures, ENB refers to $\overline{EN}$. A high level on this pin allows forcing off the internal switch and drastically decreases the current consumption of the NCP398 core. To exit the OFF state, the $\overline{EN}$ pin must be tied low.

Under−voltage Lockout (UVLO)

To ensure proper operation under any conditions, the device integrates an under−voltage lock out (UVLO) comparator. This block has a built−in hysteresis to provide noise immunity to transient conditions.

Over−voltage Lockout (OVLO)

To protect connected systems on V_{OUT} pin from over−voltage, a second comparator, over−voltage lock out (OVLO), is embedded. During over−voltage condition, the output remains disabled until the input voltage drops below the OVLO – comparator hysteresis.

Auto Discharge − R_{PD}

When disabling the NCP398 the output gets automatically discharged by means of the internal pull down resistor Rpd. Once reaching the Vpd level the discharge path is disabled. The auto−discharge is also engaged when Vin drops below the UVLO threshold. The auto−discharge ensures a proper power cycling of peripherals connected to the output of the NCP398.

Thermal Shutdown Protection

In case of internal overheating, the integrated thermal shutdown (TSD) protection will open the internal NMOS FET in order to instantaneously decrease the device temperature.

Embedded hysteresis allows reengaging the NMOS FET when the junction temperature decreases.

This OFF−ON cycle is repeated until the fault event disappears.

TYPICAL CHARACTERISTICS

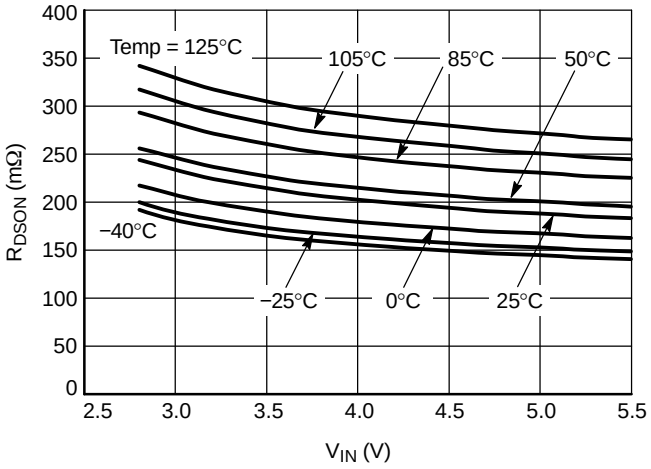


Figure 4. Ron vs. Vin, Overtemperature

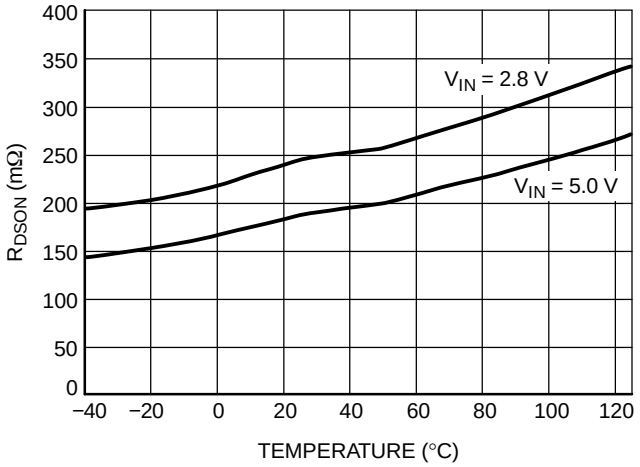


Figure 5. Ron vs. Temperature, at Fixed Vin Voltage

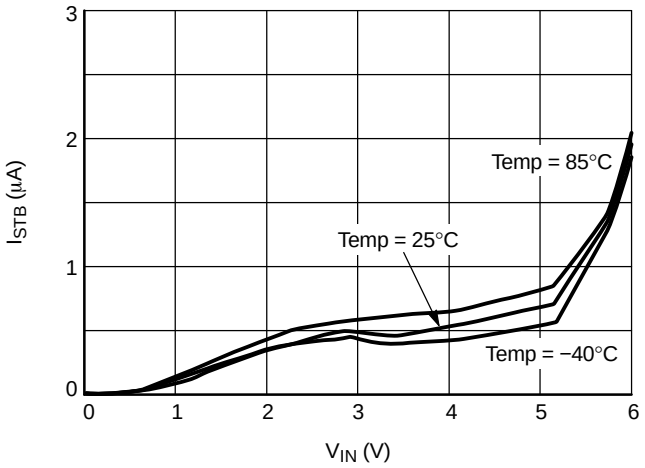


Figure 6. Standby Current vs. Vin, Over Temperature

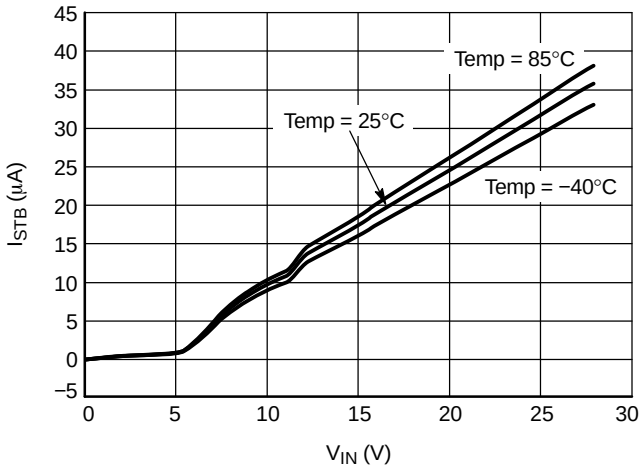


Figure 7. Standby Current vs. Vin, Over Temperature

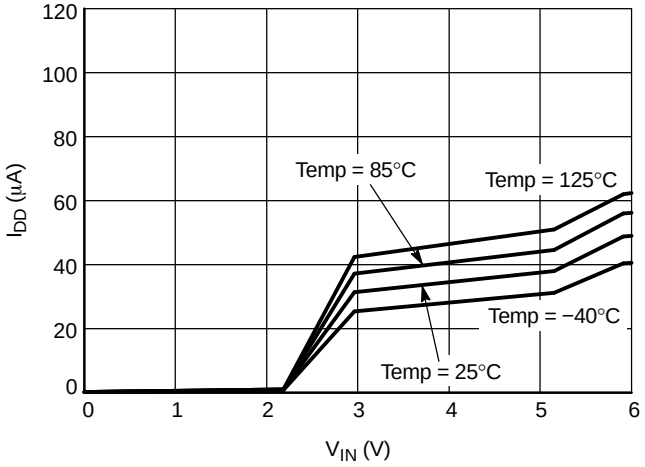


Figure 8. Quiescent Current vs. Vin, Over Temperature

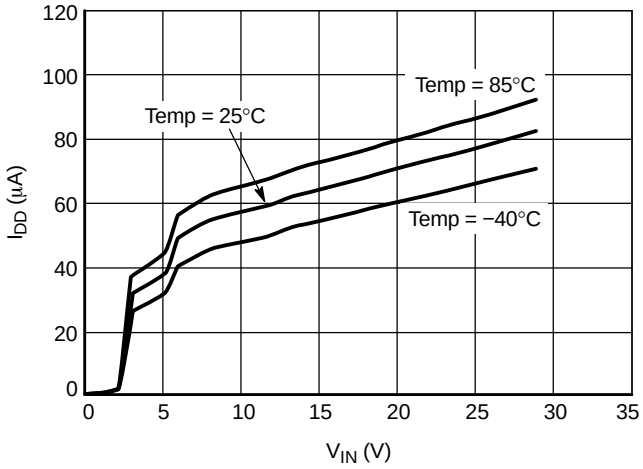


Figure 9. Quiescent Current vs. Vin, Over Temperature

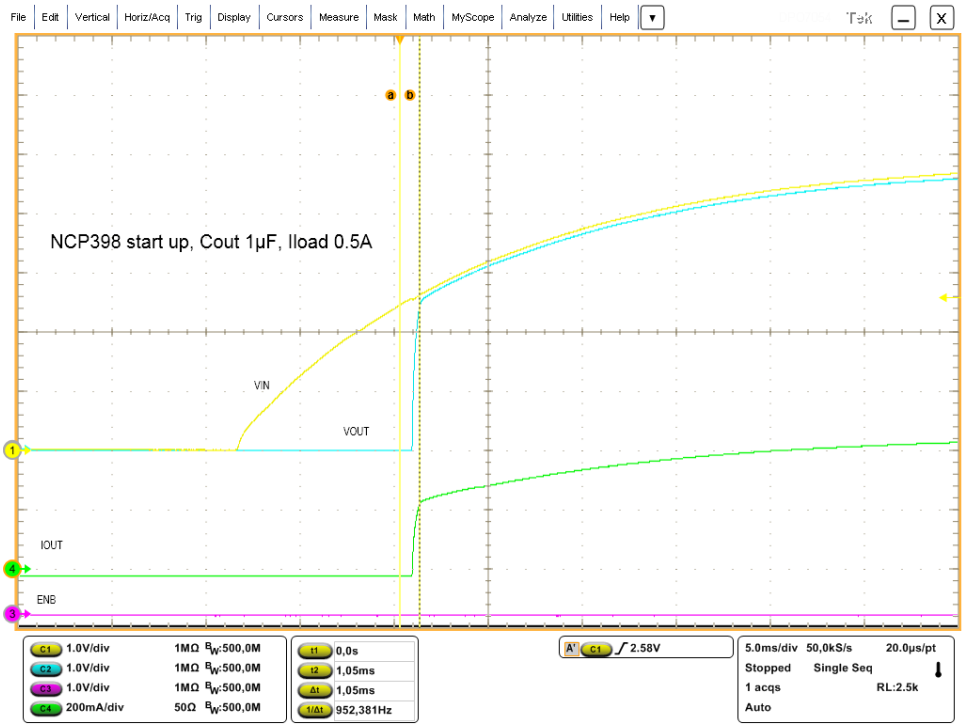


Figure 10. Soft Start Up On Load, Vin: yellow, Vout: blue, $\overline{EN}$: pink, IOUT: green

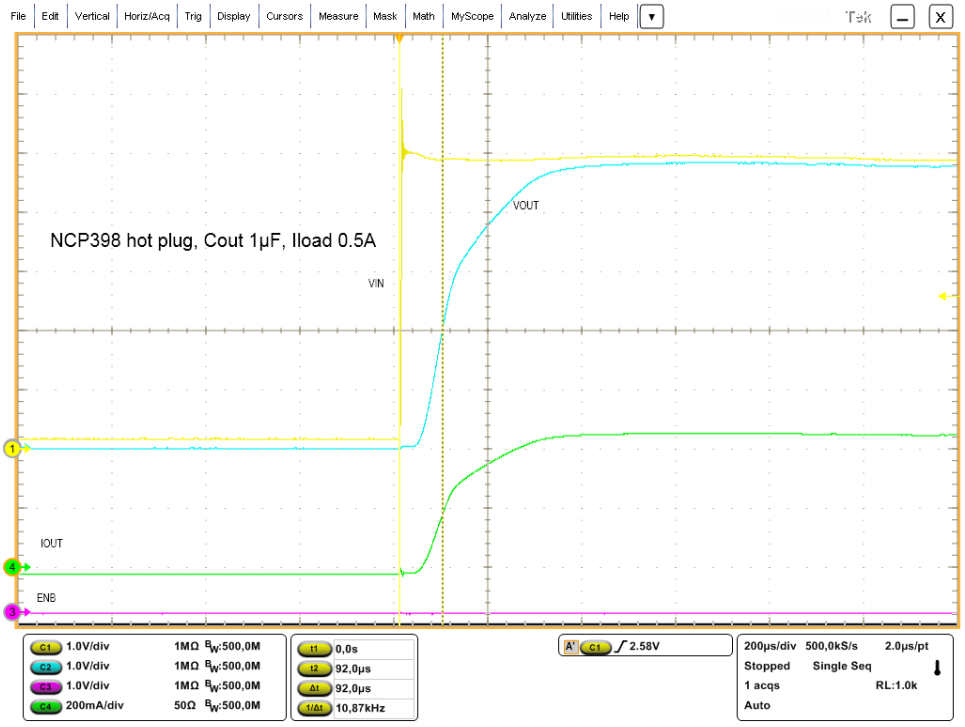


Figure 11. Hot Plug On Load, Vin: yellow, Vout: blue, $\overline{EN}$: pink, IOUT: green

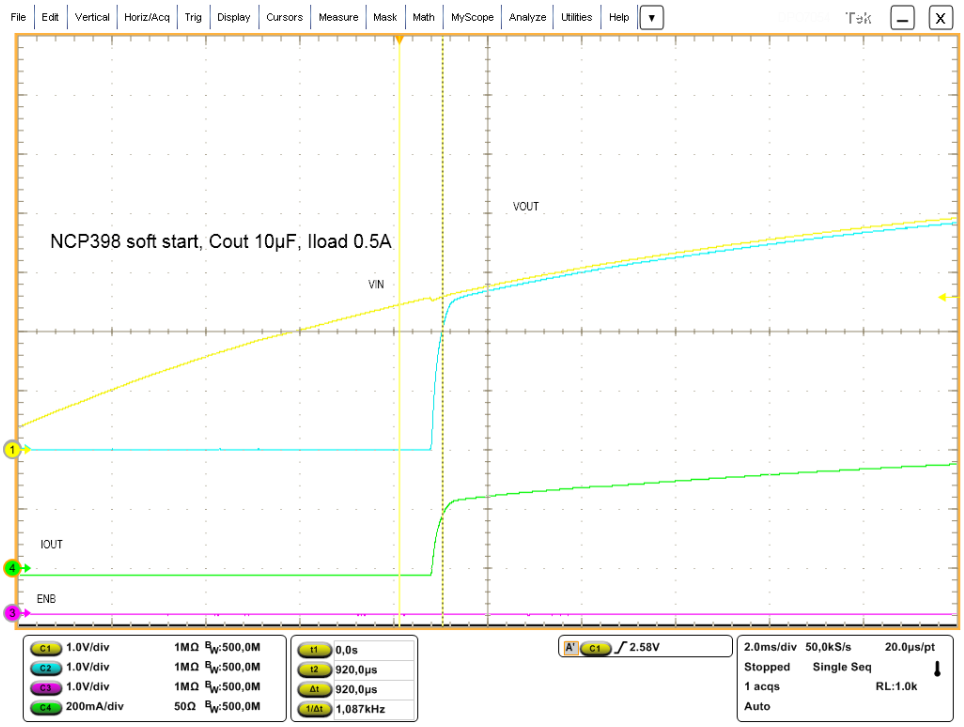


Figure 12. Soft Start On Cout 10 µF, 500 mA, Vin: yellow, Vout: blue, $\overline{EN}$: pink, IOUT: green

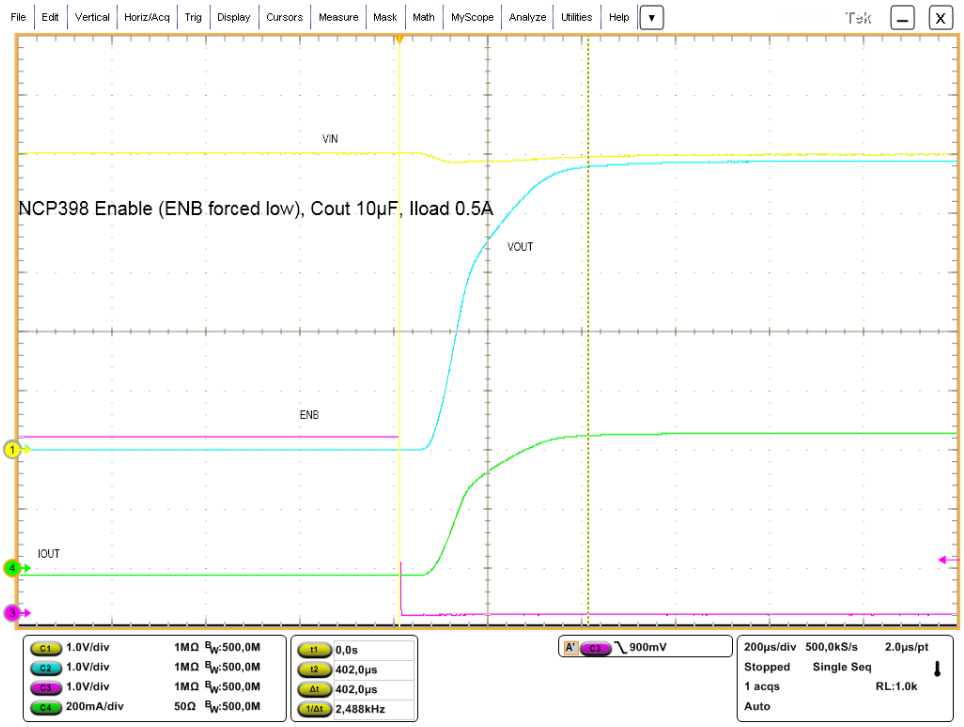


Figure 13. NCP398 Enable (ENB forced low) Vin: yellow, Vout: blue, $\overline{EN}$: pink, IOUT: green

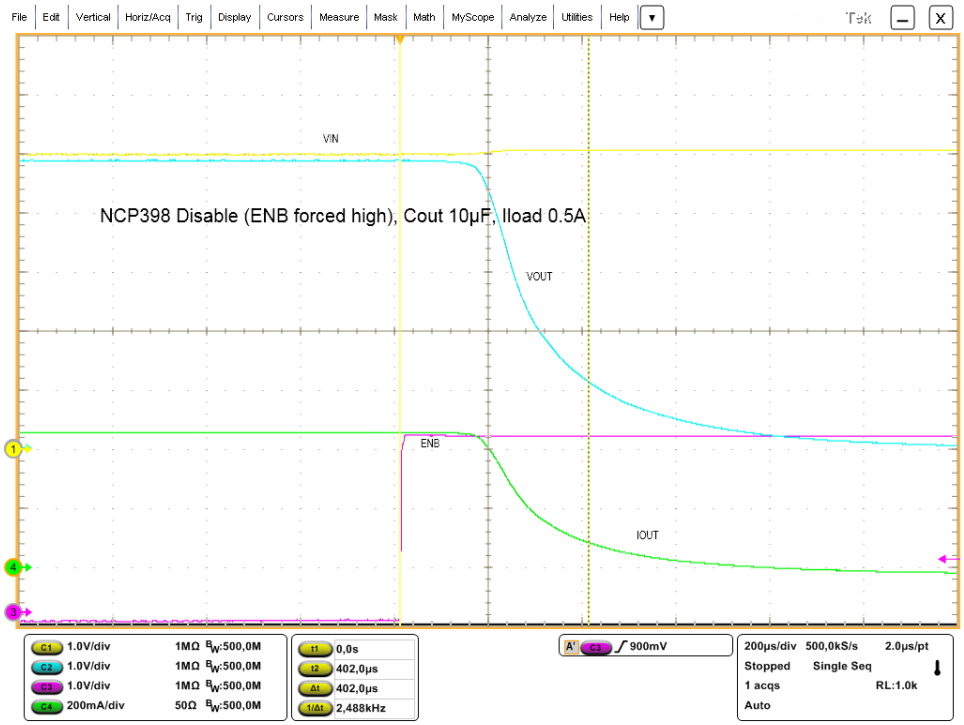


Figure 14. NCP398 Disable (ENB forced high) Vin: yellow, Vout: blue, $\overline{EN}$: pink, IOUT: green

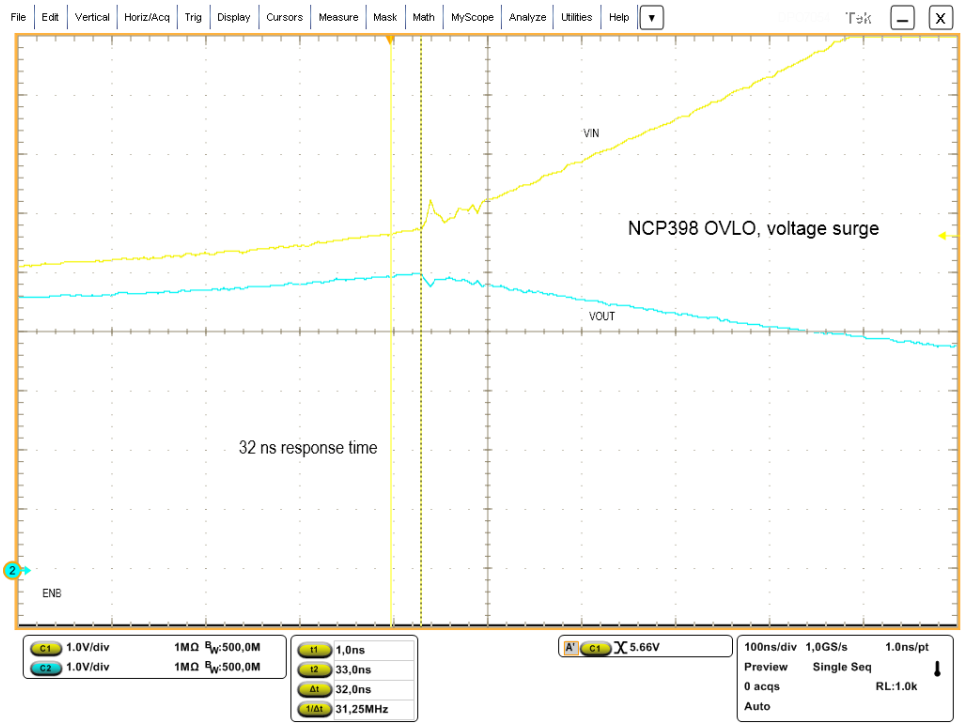


Figure 15. NCP398 Overvoltage Time Response, Vin: yellow, Vout: blue

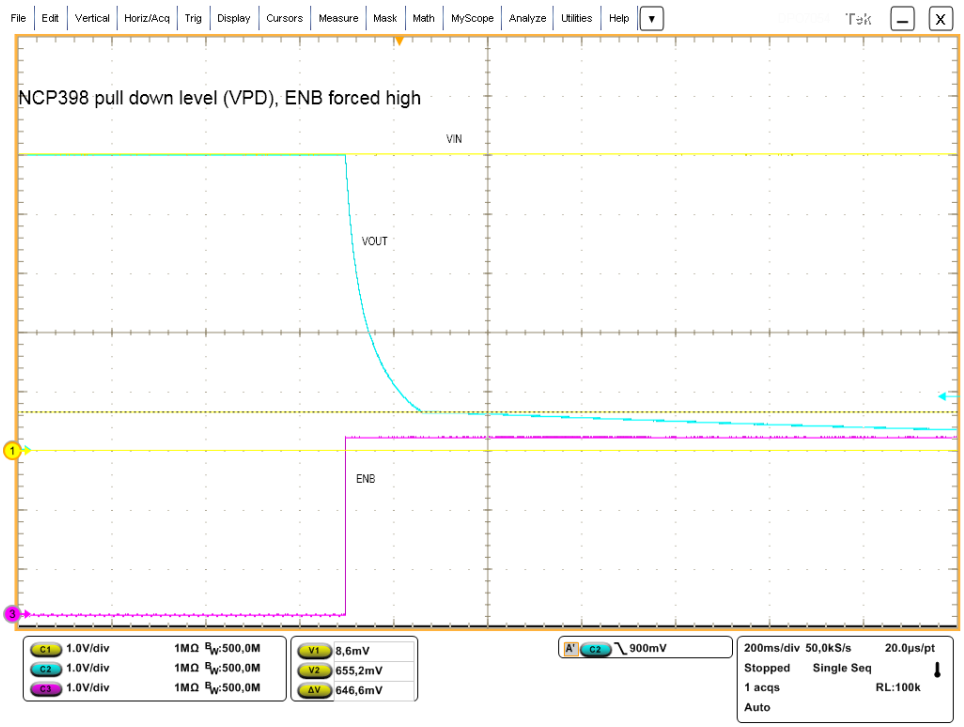


Figure 16. NCP398 Pull Down Level (following disable) Vin: yellow, Vout: blue, $\overline{EN}$: pink

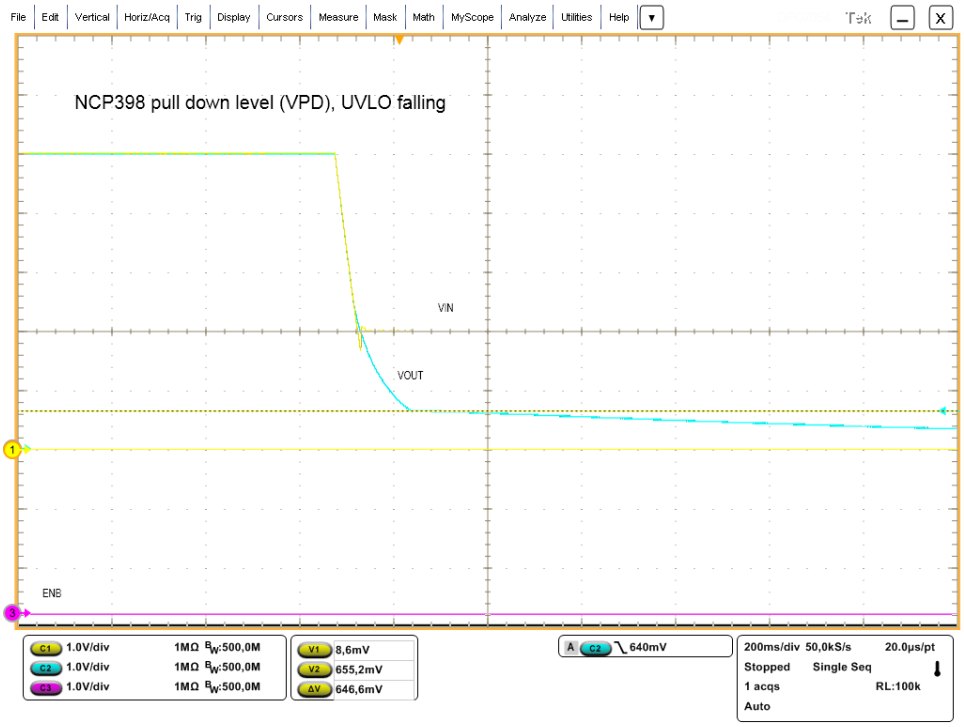


Figure 17. NCP398 Pull Down Level (following UVLO) Vin: yellow, Vout: blue, $\overline{EN}$: pink

ORDERING INFORMATION

Device	Marking	Package	Shipping†
NCP398FCCT1G	AA	WLCSP4 0.84x0.84 mm	3000 Tape / Reel
NCP398MUTBG	AV	UDFN6 2x2 mm	3000 Tape / Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

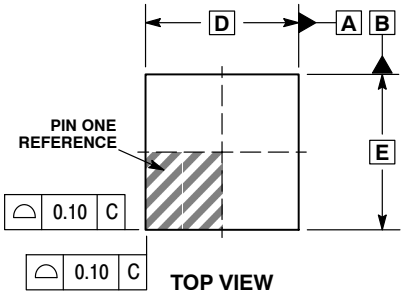
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

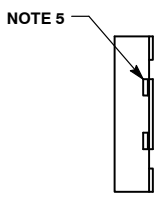
SCALE 4:1

UDFN6 2x2, 0.65P
CASE 517AB
ISSUE C

DATE 10 APR 2013



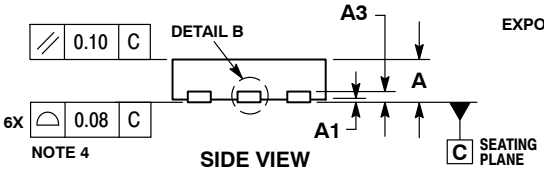
TOP VIEW



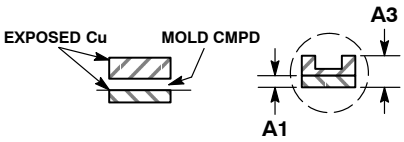
END VIEW

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.25MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. TIE BARS MAY BE VISIBLE IN THIS VIEW AND ARE CONNECTED TO THE THERMAL PAD.

DIM	MILLIMETERS	
	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.127 REF	
b	0.25	0.35
D	2.00 BSC	
D2	1.50	1.70
E	2.00 BSC	
E2	0.80	1.00
e	0.65 BSC	
L	0.25	0.35
L1	---	0.15



SIDE VIEW



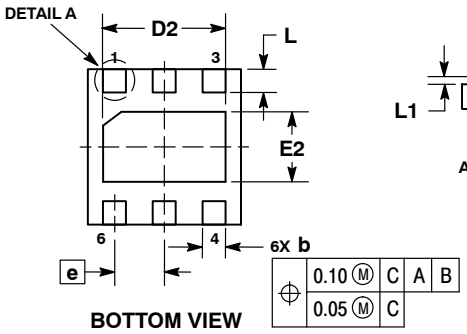
DETAIL B
ALTERNATE CONSTRUCTIONS

GENERIC MARKING DIAGRAM*

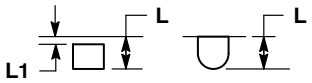
XX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

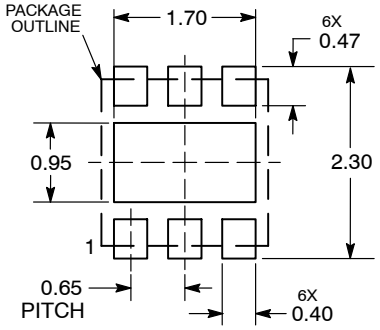


BOTTOM VIEW



DETAIL A
ALTERNATE TERMINAL CONSTRUCTIONS

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON22162D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	UDFN6 2X2, 0.65P	PAGE 1 OF 1

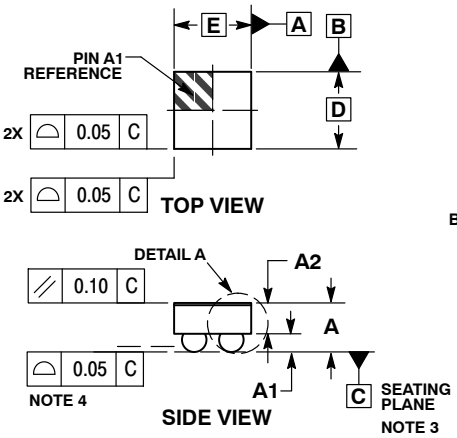
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

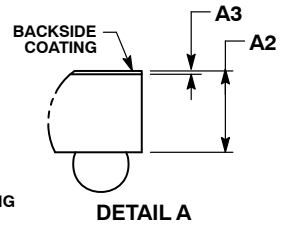
ON Semiconductor®

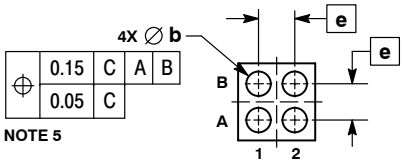
SCALE 4:1

WLCSP4, 0.84x0.84
CASE 567MN
ISSUE A

DATE 01 SEP 2016



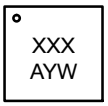




NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DATUM C, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE CONTACT BALLS.
4. COPLANARITY APPLIES TO SPHERICAL CROWNS OF CONTACT BALLS.
5. DIMENSION b IS MEASURED AT THE MAXIMUM CONTACT BALL DIAMETER PARALLEL TO DATUM C.

	MILLIMETERS	
DIM	MIN	MAX
A	---	0.60
A1	0.18	0.22
A2	0.34 REF	
A3	0.02 REF	
b	0.24	0.30
D	0.84 BSC	
E	0.84 BSC	
e	0.40 BSC	

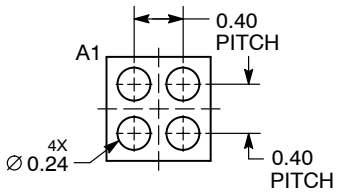
GENERIC MARKING DIAGRAM*



A = Assembly Location
Y = Year
W = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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